## DATA SHEET

## CBT6820

20-bit bus switch with precharged outputs and Schottky undershoot protection for live insertion

## 20-bit bus switch with precharged outputs and Schottky undershoot protection for live insertion

## FEATURES

- TTL compatible inputs and outputs
- $5 \Omega$ switch connection between two port A and port B
- Thin shrink small outline (TSSOP)
- Undershoot protection included to prevent shoot through level changes
- Bias voltage pre-charges the outputs to minimize signal distortion during live insertion


## DESCRIPTION

The CBT6820 provides twenty bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows bi-directional connections to be made while adding near-zero propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The device is organized as two 10 -bit switch with individual enable (OE) input. When OE is low, the switch is on and port A is connected to port B . When OE is high, the switch between port A and port $B$ is open and the $B$ port is precharged to BIASV through the equivalent of a $10-\mathrm{k} \Omega$ resistor.
Special clamp circuitry and Schottky diode clamps to ground are used to prevent an under voltage on the A side (Vin < GND) from causing the $B$ side precharge voltage to drop below the " 1 " state.

## PIN CONFIGURATION



## QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS <br> $\mathbf{T}_{\text {amb }}=25^{\circ} \mathbf{C} ; \mathbf{G N D}=\mathbf{0 V}$ | TYPICAL | UNIT |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{t}_{\mathrm{PLH}} / \mathrm{t}_{\text {PHL }}$ | Propagation delay <br> An to Bn or Bn to An | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | 0.25 | ns |
| $\mathrm{C}_{\mathrm{IN}}$ | Input capacitance |  | 4.5 | pF |
| $\mathrm{C}_{\mathrm{I} / \mathrm{O}}$ | Input/output capacitance | Outputs disabled; $\mathrm{V}_{\mathrm{O}}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{CC}}$ | 9.5 | pF |

## ORDERING INFORMATION

| PACKAGES | TEMPERATURE RANGE | OUTSIDE NORTH AMERICA | NORTH AMERICA | DWG NUMBER |
| :---: | :---: | :---: | :---: | :---: |
| 48 -Pin Plastic TSSOP Type II | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | CBT6820 DGG | CBT6820 DGG | SOT362- 1 |

## PIN DESCRIPTION

| PIN NUMBER | SYMBOL | NAME AND FUNCTION |
| :---: | :---: | :--- |
| 1 | BIASV | Bias voltage |
| $2,3,4,5,6$, <br> $7,9,10,11,12$ | $1 \mathrm{~A} 1-1 \mathrm{~A} 10$ | Port 1A1 to Port 1A10 |
| $8,17,32,41$ | GND | Ground (V) |
| $13,14,16,18,19$, <br> $20,21,22,23,24$ | $2 \mathrm{~A} 1-2 \mathrm{~A} 10$ | Port 2A1 to Port 2A10 |
| 15 | V CC | Positive supply voltage |
| $35,34,33,31,30$, <br> $29,28,27,26,25$ | $2 \mathrm{~B} 1-2 \mathrm{~B} 10$ | Port 2B1 to Port 2B10 |
| $46,45,44,43,42$, <br> $40,39,38,37,36$ | $1 \mathrm{~B} 1-1 \mathrm{~B} 10$ | Port 1B1 to Port 1B10 |
| 48,47 | $1 \overline{\mathrm{OE}, 2 \overline{\mathrm{OE}}}$ | Switch enables |

FUNCTION TABLE

| $\overline{\text { OE }}$ | STATE |
| :---: | :---: |
| L | A Port $=$ B Port |
| H | A Port $=$ Z |
| H | B Port $=$ BIASV |

$\mathrm{H}=$ High voltage level
L = Low voltage level

## LOGIC SYMBOL



Z = High impedance "off" state

## ABSOLUTE MAXIMUM RATINGS

| SYMBOL | PARAMETER | CONDITIONS | RATING | UNIT |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC supply voltage |  | -0.5 to +7.0 | V |
| $\mathrm{I}_{\mathrm{IK}}$ | DC clamp diode current | $\mathrm{V}_{\mathrm{I}}<0$ | -50 | mA |
| $\mathrm{~V}_{\mathrm{I}}$ | DC input voltage ${ }^{1}$ |  | -0.5 to +7.0 | V |
| $\mathrm{I}_{\text {SW }}$ | DC continuous channel current | $\mathrm{V}_{\mathrm{O}}=0$ to $\mathrm{V}_{\mathrm{CC}}$ | $\pm 128$ | mA |
| $\mathrm{~V}_{\text {BIASV }}$ | DC bias voltage |  | -0.5 to +7.0 | V |
| $\mathrm{~T}_{\text {stg }}$ | Storage temperature range | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |  |
| $\varnothing \mathrm{JA}$ | Plastic thin shrink small outline package <br> (TSSOP) |  | 104 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | LIMITS |  | UNIT |
| :---: | :--- | :---: | :---: | :---: |
|  |  | Min | Max |  |
| $\mathrm{V}_{\mathrm{CC}}$ | DC supply voltage | 4.0 | 5.5 | V |
| BIASV | DC supply voltage | 1.3 | $\mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage (control pin) | 2.0 |  | V |
| $\mathrm{~V}_{\mathrm{IL}}$ | Low-level Input voltage (control pin) |  | 0.8 | V |
| $\mathrm{~T}_{\text {amb }}$ | Operating free-air temperature range | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |

20-bit bus switch with precharged outputs and Schottky undershoot protection for live insertion

## DC ELECTRICAL CHARACTERISTICS

| SYMBOL | PARAMETER | TEST CONDITIONS | LIMITS |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{Tamb}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ ${ }^{1}$ | Max |  |
| $\mathrm{V}_{\mathrm{IK}}$ | Input clamp voltage | $\mathrm{V}_{C C}=4.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{I}}=-18 \mathrm{~mA}$ |  |  | -1.2 | V |
| 1 | Input leakage current (control pin) | $\mathrm{V}_{\text {CC }}=5.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{I}}=\mathrm{GND}$ or 5.5 V |  |  | $\pm 5$ | $\mu \mathrm{A}$ |
| Io | Output bias current (B pins) | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} ; \operatorname{Bias} \mathrm{V}=2.4 \mathrm{~V} ; \mathrm{V}_{\mathrm{O}}=0, \overline{O E}=\mathrm{V}_{\mathrm{CC}}$ |  |  | -0.25 | mA |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent supply current | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V} ; \mathrm{l}_{\mathrm{O}}=0, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}}$ or GND |  |  | 2.5 | mA |
| $\Delta_{\text {l }}$ | Control pins ${ }^{2}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, one input at 3.4 V , other inputs at $\mathrm{V}_{\mathrm{CC}}$ or GND |  |  | 2.5 | mA |
| $\mathrm{C}_{1}$ | Input capacitance per $\overline{O E}$ pin | $\mathrm{V}_{1}=3 \mathrm{~V}$ or 0 |  | 4.5 |  | pF |
| $\mathrm{C}_{\text {O(OFF) }}$ | Capacitance per port (OFF-state) | $\mathrm{V}_{\mathrm{O}}=3 \mathrm{~V}$ or 0; switch off |  | 9.5 |  | pF |
| $\mathrm{ron}^{3}$ | On-resistance | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{I}}=0 \mathrm{~V} ; \mathrm{I}_{\mathrm{I}}=64 \mathrm{~mA}$ |  | 5 | 7 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{I}}=0 \mathrm{~V} ; \mathrm{I}_{\mathrm{I}}=30 \mathrm{~mA}$ |  | 5 | 7 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V} ; \mathrm{I}_{\mathrm{I}}=-15 \mathrm{~mA}$ |  | 10 | 15 |  |
| $\mathrm{V}_{\mathrm{P}}$ | Pass voltage | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V} ; \mathrm{I}_{\text {out }}=-100 \mu \mathrm{~A}$ | 3.4 | 3.6 | 3.9 | V |
| IUSP | Undershoot static current protection ${ }^{4}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{Bias}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{B}}=-5 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{B}} \geq 3.0 \mathrm{~V} \end{aligned}$ |  | -10 |  | mA |

## NOTES:

1. All typical values are at $\mathrm{VCC}=5 \mathrm{~V}, \mathrm{TA}=25 \mathrm{C}$
2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than $\mathrm{V}_{C C}$ or GND
3. Measured by the voltage drop between the $A$ and the $B$ terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.
4. Force lusp, measure $\mathrm{V}_{\mathrm{B}} \geq 3 \mathrm{~V}$

## AC CHARACTERISTICS FOR $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}$ RANGE

GND $=0 \mathrm{~V} ; \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns} ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$.

| SYMBOL | PARAMETER | WAVEFORM |  | LIMITS |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{T}_{\mathrm{amb}}=-40$ to $+85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | MIN | TYP ${ }^{1}$ | MAX |  |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation delay; An to Bn ; Bn to $\mathrm{An}^{2}$ | 1 |  |  | 0.25 | ns |
| tpZH | 3-State output enable time OE to An; OE to Bn; BIASV = GND | 2 | 1.3 | 3.1 | 5.3 | ns |
| $t_{\text {PZL }}$ | 3-State output enable time OE to An; OE to Bn; BIASV = 3.0V | 2 | 1.4 | 2.9 | 4.6 | ns |
| tPHZ | 3-State output enable time OE to An; $\overline{O E}$ to $\mathrm{Bn} ; \mathrm{BIASV}=\mathrm{GND}$ | 2 | 1.7 | 2.8 | 4.5 | ns |
| tpLZ | 3-State output enable time OE to $\mathrm{An} ; \overline{\mathrm{OE}}$ to $\mathrm{Bn} ; \mathrm{BIASV}=3.0 \mathrm{~V}$ | 2 | 2.8 | 4.4 | 6.6 | ns |

NOTE:

1. All typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$
2. Warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance)

## AC WAVEFORMS

$\mathrm{V}_{\mathrm{M}}=1.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{GND}$ to 3.0 V


Waveform 1. Waveforms Showing the Input (An) to Output (Bn) Propagation Delays


Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS

defintions
$C_{L}=$ Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value

## NOTES:

1. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.
2. The outputs are measured one at a time with one transition per measurement.



detail X


DIMENSIONS (mm are the original dimensions).

| UNIT | A max. | $\mathrm{A}_{1}$ | $\mathrm{A}_{2}$ | $\mathrm{A}_{3}$ | $\mathbf{b}_{\mathrm{p}}$ | c | $\mathrm{D}^{(1)}$ | $E^{(2)}$ | e | $\mathrm{HE}_{\mathrm{E}}$ | L | $L_{p}$ | Q | v | w | y | Z | $\theta$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.2 | $\begin{aligned} & 0.15 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & 1.05 \\ & 0.85 \end{aligned}$ | 0.25 | $\begin{aligned} & 0.28 \\ & 0.17 \end{aligned}$ | $\begin{aligned} & 0.2 \\ & 0.1 \end{aligned}$ | $\begin{aligned} & 12.6 \\ & 12.4 \end{aligned}$ | $\begin{aligned} & 6.2 \\ & 6.0 \end{aligned}$ | 0.5 | $\begin{aligned} & 8.3 \\ & 7.9 \end{aligned}$ | 1 | $\begin{aligned} & 0.8 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & 0.50 \\ & 0.35 \end{aligned}$ | 0.25 | 0.08 | 0.1 | 0.8 0.4 | 8 $0^{\circ}$ |

## Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.


## NOTES

## DEFINITIONS

| Data Sheet Identification | Product Status | Definition |
| :---: | :---: | :--- |
| Objective Specification | Formative or in Design | This data sheet contains the design target or goal specifications for product development. Specifications <br> may change in any manner without notice. |
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